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Technical Note 4048

Effective December 2017 Supersedes 2009

Transient Voltage Suppression diode application notes





TVSA Family: available in 0201 and 0402 SMD packages

Overview

Transient Voltage Suppression (TVS) diodes are useful in protecting electronic circuits from electrostatic discharge (ESD). The TVS diodes used for ESD protection are silicon-avalanche diodes.

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With a high impedance at the stand-off voltage and low impedance at the breakdown voltage, silicon-avalanche diodes are well suited for ESD protection.

To better understand the TVS diode's application for ESD protection, one must first understand how the diode works in general and, in particular, how the silicon-avalanche diode differs from the Zener diode.

Silicon-Avalanche Diode vs. Zener Diode

Silicon-avalanche diodes (SADs) are similar to Zener diodes. SADs are even sometimes mistaken for Zener diodes because of their similar electrical characteristics. The Zener diode and SADs both conduct in the reverse direction if the voltage through it exceeds a set breakdown voltage.

Zener diode: This corresponds to the transport of electrons from the positively doped side of the diode to the holes of the negatively doped side of the diode (Figure 1). SAD: A similar transport of electrons occurs called the avalanche effect. The only real difference between the Zener diode and SAD is the length of the p-n equilibrium channel (Figure 2).

Here the only real difference is seen is the temperature coefficients:

- Zener diodes have a negative temperature coefficient, (resistance decreases and temperature increases)
- SADs have a positive temperature coefficient (resistance increases and temperature increases)

This, however, is only important in temperature sensitive applications.



Figure 1. Zener diode







TVS diodes

TVS diodes tend to be designed with silicon-avalanche technology. To provide full protection of the device against both positive and negative voltage spikes, the TVS is constructed using two opposing SADs in series (Figure 3).



Figure 3. Bi-directional TVS circuit symbol

Applications

TVS diodes serve many uses in electronic applications to suppress voltage spikes and protect against ESD damage. Eaton offers the TVSA family of TVS diodes that can be used in many applications including computers and peripherals, digital still cameras, mobile phones, portable electronics, DVD players, media players, external storage, set top boxes and docking systems.

Features

Eaton's TVSA Family is RoHS compliant and lead free for global applications with excellent ESD protection as tested by IEC 61000-4-2 level 4 test.

Eaton offers some of the only SMD, low profile TVS diodes available in 0201 and 0402 sizes. The TVSA family features very low clamping voltages for increased device protection from overvoltage events. The TVSA family also provides comparatively low capacitance compared to many other diode-based solutions and the low leakage current minimizes power consumption.

TVSA Specifications*

Part numbers: TVSA02V05C004 (0201 size) TVSA04V05C006 (0402 size)

Technology:

• Transient voltage suppression via solid-state siliconavalanche diode technology

Electrical Characteristics:

- Reverse Stand-off Voltage: 5 Vdc
- Reverse Breakdown Voltage: 10 Vdc
- Capacitance: 4 pF (0201)

6 pF (0402)

ESD Capability:

- IEC61000-4-2 Direct Discharge: 8 kV
- IEC61000-4-2 Air Discharge: 15 kV
- * For complete product details see Data sheet DS4072 online at

www.eaton.com/electronics

Order samples on-line: tools.eatonelectronics.com/request-form

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TVSA Family dimensions - mm



Design Considerations

The location in the circuit for the TVSA family has to be carefully determined. For better performance, the device should be placed as close to the signal input as possible and ahead of any other component. Due to the high current associated with an ESD event, it is recommended to use a "0-stub" pad design (pad directly on the signal/data line and second pad directly on common ground).

To properly specify an Eaton TVSA family diode, a few things need to be taken into consideration. First is knowing the circuit's data speed and/or the maximum tolerable circuit capacitance. This is extremely important when deciding if it is practical to use a TVS diode solution.

For example, in protecting a USB 2.0 port, the TVSA capacitances of 4-6 pF are not practical, as this high capacitance may distort the data signal.

Another important consideration is knowing the voltage the circuit can withstand without incurring damage. The TVSA clamping voltage rating should be below this voltage.

The clamping voltage is the peak voltage across the TVS diode at the peak current of an 8/20 µs waveform with 1 A pulse current (Figure 4).

The final consideration when specifying a TVS diode is the circuit's normal operating voltage. It is beneficial to have the TVSA stand-off voltage (the maximum voltage where the leakage current does not exceed 10 µA) above the normal operating current of the circuit. This ensures the low leakage current of the TVS diode.



Figure 4. 8/20 µs waveform

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December 2017

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